NSN 5961-01-135-0715

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-135-0715 **Inclosure Material:** Metal **Overall Length:** 2.500 inches **Overall Diameter:** 1.210 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.245 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 250.00 amperes collector current, dc **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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